

Sensitivity and Dynamic Range: Sensitivity

- The sensitivity is defined as the minimum signal level that a receiver can detect with “acceptable quality.”

$$\begin{aligned} NF &= \frac{SNR_{in}}{SNR_{out}} \\ &= \frac{P_{sig}/P_{RS}}{SNR_{out}} \end{aligned}$$

$$P_{sig} = P_{RS} \cdot NF \cdot SNR_{out}$$

$$P_{sig,tot} = P_{RS} \cdot NF \cdot SNR_{out} \cdot B$$

$$P_{sen}|_{dBm} = P_{RS}|_{dBm/Hz} + NF|_{dB} + SNR_{min}|_{dB} + 10 \log B$$

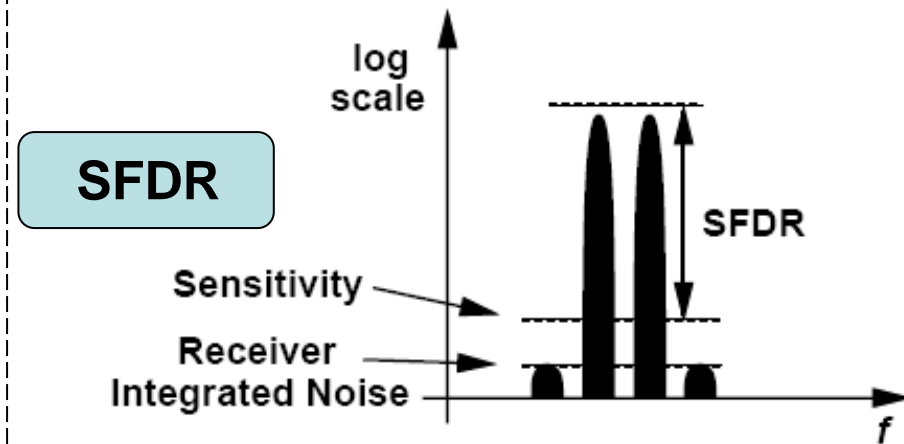
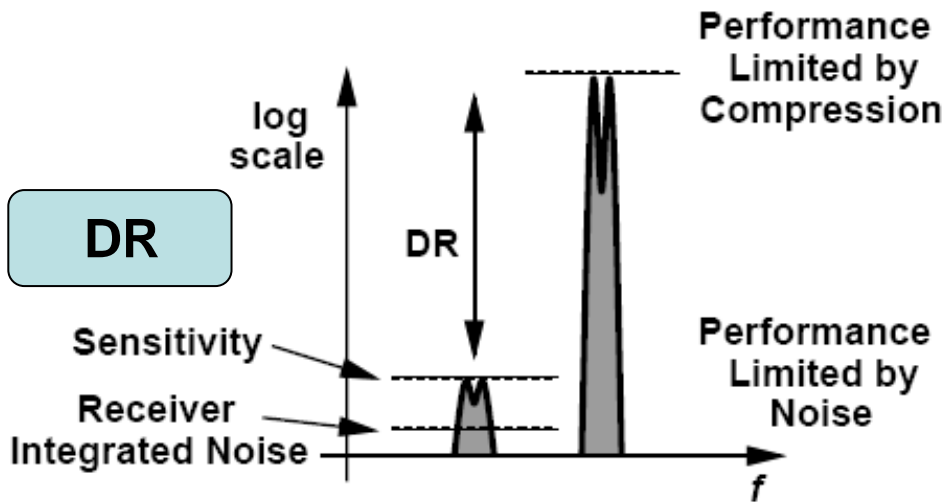
$$P_{sen} = -174 \text{ dBm/Hz} + \underbrace{NF + 10 \log B + SNR_{min}}_{\text{Noise Floor}}$$

Noise Floor

Example of Sensitivity

A GSM receiver requires a minimum SNR of 12 dB and has a channel bandwidth of 200 kHz. A wireless LAN receiver, on the other hand, specifies a minimum SNR of 23 dB and has a channel bandwidth of 20 MHz. Compare the sensitivities of these two systems if both have an NF of 7 dB.

Dynamic Range Compared with SFDR



➤ **Dynamic Range:**
Maximum tolerable desired signal power divided by the minimum tolerable desired signal power

➤ **SFDR:**
Lower end equal to sensitivity.
Higher end defined as maximum input level in a *two-tone* test for which the third-order IM products do not exceed the integrated noise of the receiver

SFDR Calculation

Refer output IM magnitudes to input:

$$P_{IIP3} = P_{in} + \frac{P_{out} - P_{IM,out}}{2}$$

$$P_{IM,in} = P_{IM,out} - G \quad P_{in} = P_{out} - G$$

$$P_{IIP3} = P_{in} + \frac{P_{in} - P_{IM,in}}{2}$$

$$= \frac{3P_{in} - P_{IM,in}}{2},$$

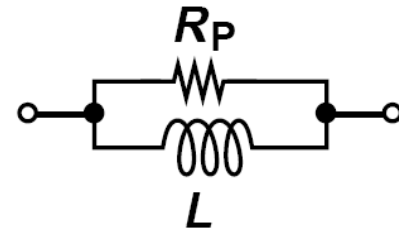
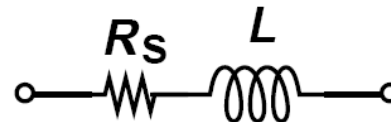
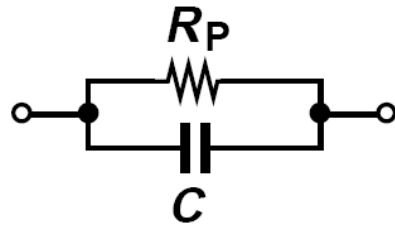
$$P_{in} = \frac{2P_{IIP3} + P_{IM,in}}{3}.$$

$$P_{in,max} = \frac{2P_{IIP3} + (-174 \text{ dBm} + NF + 10 \log B)}{3}.$$

$$\begin{aligned} SFDR &= P_{in,max} - (-174 \text{ dBm} + NF + 10 \log B + SNR_{min}) \\ &= \frac{2(P_{IIP3} + 174 \text{ dBm} - NF - 10 \log B)}{3} - SNR_{min}. \end{aligned}$$

Passive Impedance Transformation: Quality Factor

➤ Quality Factor, Q , indicates how close to ideal an energy-storing device is.



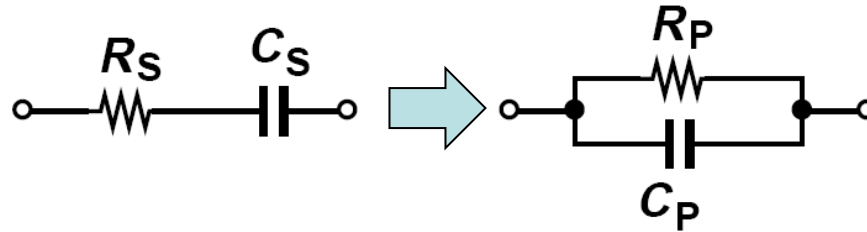
$$Q_S = \frac{1}{\frac{C\omega}{R_S}}$$

$$Q_P = \frac{R_P}{\frac{1}{C\omega}}$$

$$Q_S = \frac{L\omega}{R_S}$$

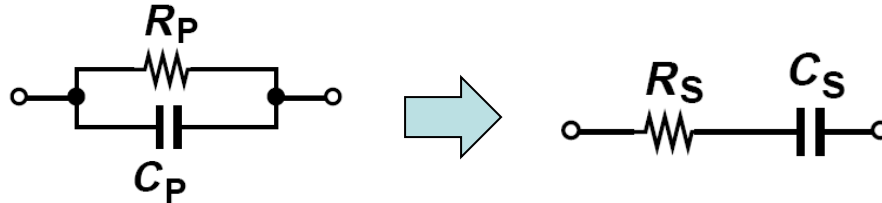
$$Q_P = \frac{R_P}{L\omega}$$

Series-to-Parallel Conversion



$$\frac{R_S C_S s + 1}{C_S s} = \frac{R_P}{R_P C_P s + 1}$$

Parallel-to-Series Conversion



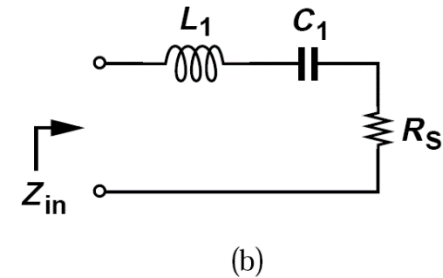
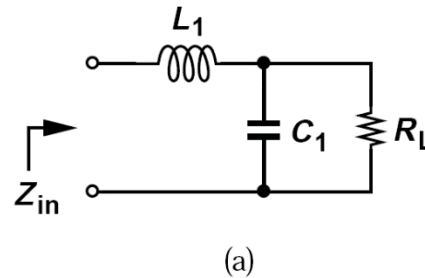
$$R_S = \frac{R_P}{Q_P^2}$$

$$C_S = C_P$$

- **Series-to-Parallel Conversion:** will retain the value of the capacitor but raises the resistance by a factor of Q_s^2
- **Parallel-to-Series Conversion:** will reduce the resistance by a factor of Q_p^2

Basic Matching Networks

$$Z_{in}(j\omega) = \frac{R_L(1 - L_1C_1\omega^2) + jL_1\omega}{1 + jR_LC_1\omega}$$



Thus,

$$\begin{aligned} \operatorname{Re}\{Z_{in}\} &= \frac{R_L}{1 + R_L^2 C_1^2 \omega^2} \\ &= \frac{R_L}{1 + Q_P^2}, \end{aligned}$$

← **R_L transformed down by a factor**

$$\begin{aligned} L_1 &= \frac{R_L^2 C_1}{1 + R_L^2 C_1^2 \omega^2} \\ &= \frac{R_L^2 C_1}{1 + Q_P^2}. \end{aligned}$$

← **Setting imaginary part to zero**

If $Q_P^2 \gg 1$

$$\begin{aligned} \operatorname{Re}\{Z_{in}\} &\approx \frac{1}{R_L C_1^2 \omega^2} \\ L_1 &= \frac{1}{C_1 \omega^2}. \end{aligned}$$

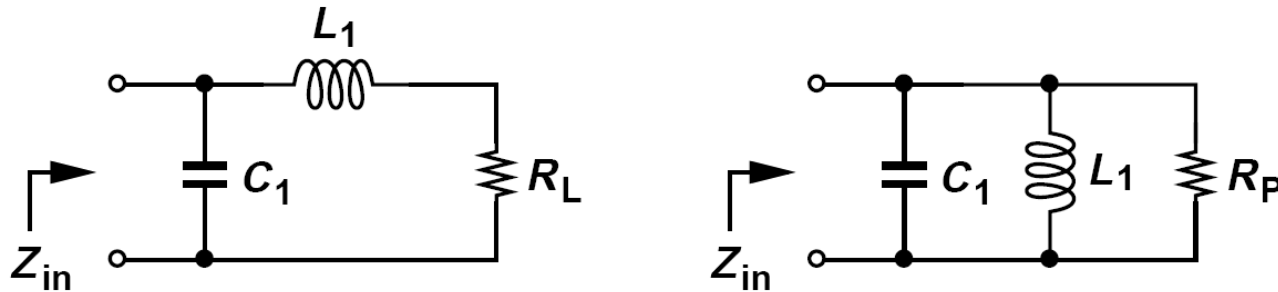
Example of Basic Matching Networks

Design the matching network of figure above so as to transform $R_L = 50\ \Omega$ to $25\ \Omega$ at a center frequency of 5 GHz.

Another Example of Basic Matching Networks

Determine how the circuit shown below transforms R_L .

Solution:

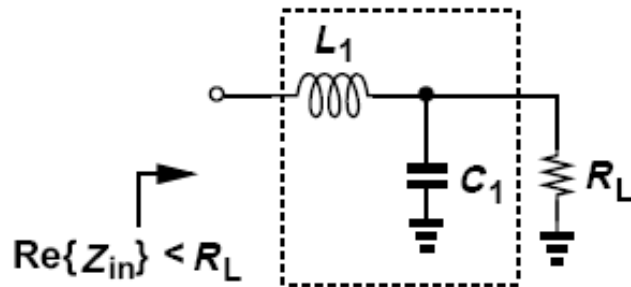


We postulate that conversion of the L_1 - R_L branch to a parallel section produces a higher resistance. If $Q_S^2 = (L_1\omega/R_L)^2 \gg 1$, then the equivalent parallel resistance is

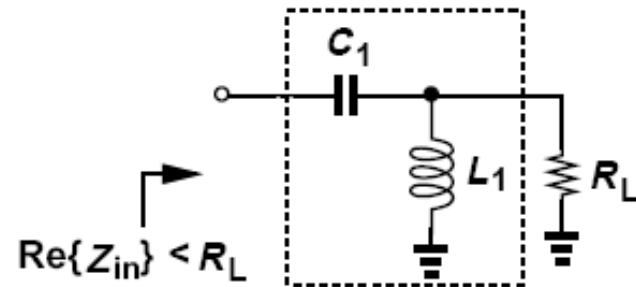
$$\begin{aligned} R_P &= Q_S^2 R_L \\ &= \frac{L_1^2 \omega^2}{R_L}. \end{aligned}$$

The parallel equivalent inductance is approximately equal to L_1 and is cancelled by C_1

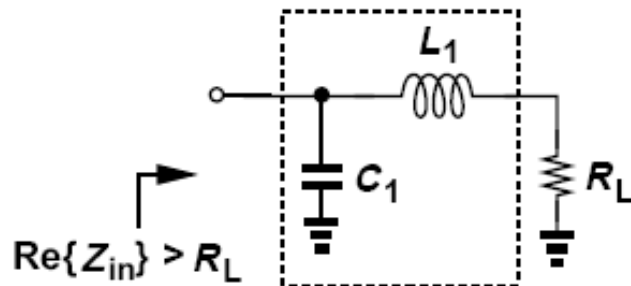
L-Sections



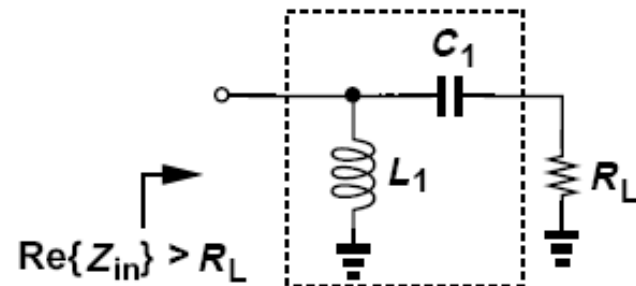
(a)



(b)



(c)



(d)

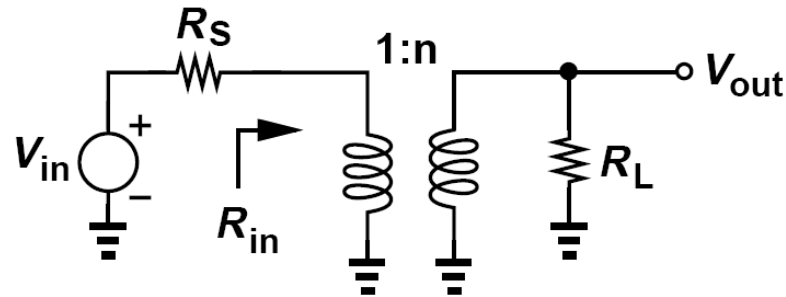
For example, in (a), we have:

$$\frac{V_{out}}{V_{in}} = \sqrt{\frac{R_L}{\text{Re}\{Z_{in}\}}}$$

$$\frac{I_{out}}{I_{in}} = \sqrt{\frac{\text{Re}\{Z_{in}\}}{R_L}}$$

a network transforming R_L to a lower value “amplifies” the voltage and attenuates the current by the above factor.

Impedance Matching by Transformers

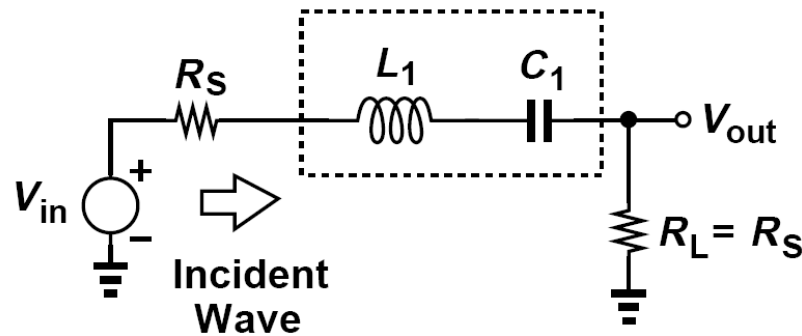


$$V_{in}^2 / R_{in} = n^2 V_{in}^2 / R_L$$

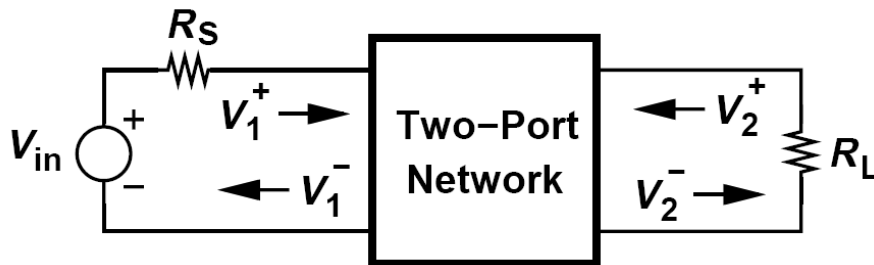
$$R_{in} = R_L / n^2$$

➤ More on this in Chapter 8

Scattering Parameters

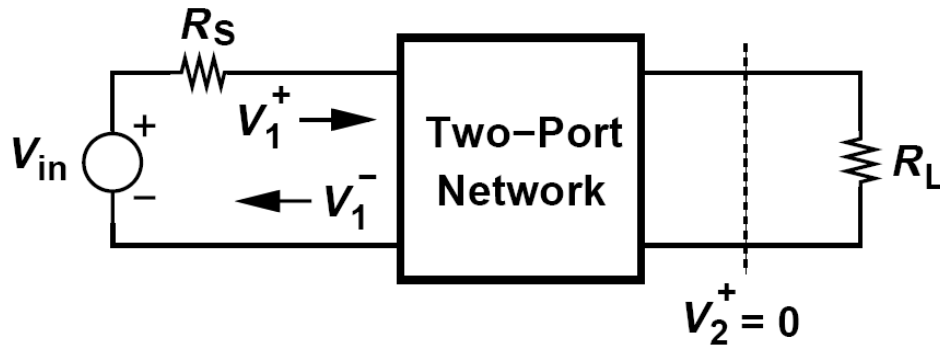


- **S-Parameter:** Use power quantities instead of voltage or current
- The difference between the incident power (the power that would be delivered to a matched load) and the reflected power represents the power delivered to the circuit.



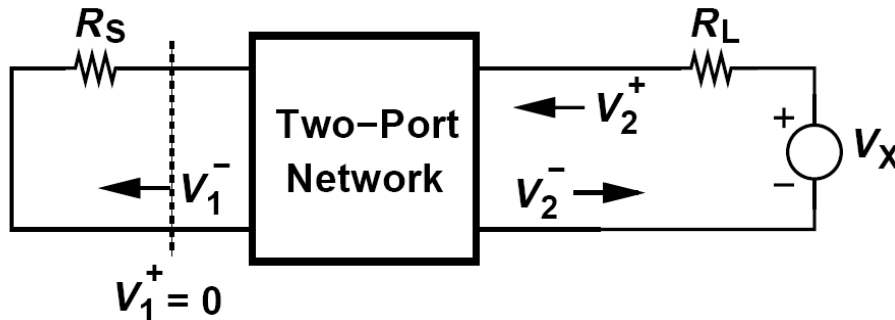
$$\begin{aligned} V_1^- &= S_{11}V_1^+ + S_{12}V_2^+ \\ V_2^- &= S_{21}V_1^+ + S_{22}V_2^+ \end{aligned}$$

S_{11} and S_{12}



$$S_{11} = \frac{V_1^-}{V_1^+} \bigg|_{V_2^+ = 0}$$

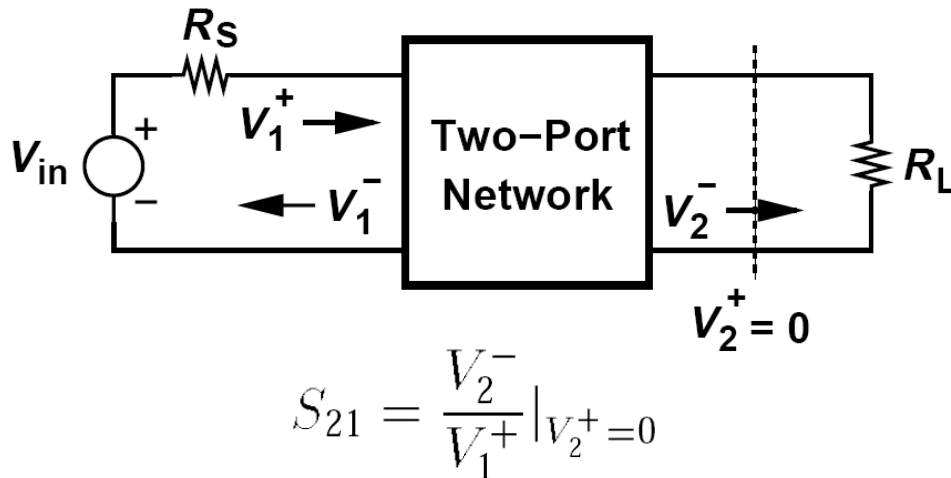
- S_{11} is the ratio of the reflected and incident waves at the input port when the reflection from R_L is zero.
- Represents the accuracy of the input matching



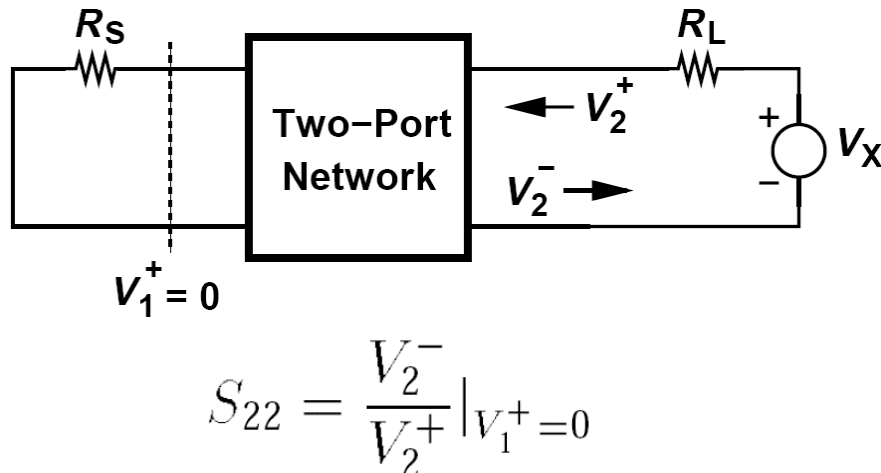
$$S_{12} = \frac{V_1^-}{V_2^+} \bigg|_{V_1^+ = 0}$$

- S_{12} is the ratio of the reflected wave at the input port to the incident wave into the output port when the input is matched
- Characterizes the *reverse isolation*

S_{21} and S_{22}



- S_{21} is the ratio of the wave incident on the load to that going to the input when the reflection from R_L is zero
- Represents the gain of the circuit



- S_{22} is the ratio of reflected and incident waves at the output when the reflection from R_s is zero
- Represents the accuracy of the output matching

Scattering Parameters: A few remarks

$$V_1^- = S_{11}V_1^+ + S_{12}V_2^+$$

$$V_2^- = S_{21}V_1^+ + S_{22}V_2^+$$

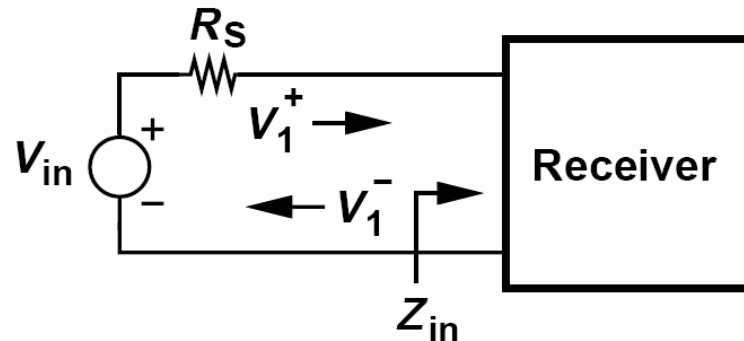
- **S-parameters generally have frequency-dependent complex values**
- **We often express S-parameters in units of dB**

$$S_{mn}|_{dB} = 20 \log |S_{mn}|$$

- **The condition $V_2^+=0$ does not mean output port of the circuit must be conjugate-matched to R_L .**

Input Reflection Coefficient

In modern RF design, S_{11} is the most commonly-used S parameter as it quantifies the accuracy of impedance matching at the input of receivers.



$$\begin{aligned} V_1^- &= V_{in} \frac{Z_{in}}{Z_{in} + R_S} - \frac{V_{in}}{2} \\ &= \frac{Z_{in} - R_S}{2(Z_{in} + R_S)} V_{in}. \end{aligned}$$

$$\frac{V_1^-}{V_1^+} = \frac{Z_{in} - R_S}{Z_{in} + R_S}$$

➤ Called the “input reflection coefficient” and denoted by Γ_{in} , this quantity can also be considered to be S_{11} if we remove the condition $V_2^+ = 0$